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Ultrafast Non-Thermal Electron Dynamics in Single Layer Graphene

D. Brida¹, C. Manzoni¹, G. Cerullo¹, A. Tomadin², M. Polini³, R. R. Nair⁴, A. K. Geim⁴, K. S. Novoselov⁴, S. Milana⁵, A. Lombardo⁵, and A. C. Ferrari⁵

¹IFN-CNR, Dipartimento di Fisica, Politecnico di Milano, Italy

² Institute for Quantum Optics and Quantum Information of the Austrian Academy of Sciences, A-6020 Innsbruck, Austria

³NEST, Istituto Nanoscienze-CNR and Scuola Normale Superiore, I-56126 Pisa, Italy

⁴Department of Physics and Astronomy, University of Manchester, Manchester M13 9 PL, UK ⁵Engineering Department, University of Cambridge, Cambridge, CB3 OFA, UK

Abstract. We study the ultrafast dynamics of non-thermal electron relaxation in graphene upon impulsive excitation. The 10-fs resolution two color pump-probe allows us to unveil the non-equilibrium electron gas decay at early times.

1 Introduction

The dynamics of elementary optical excitations in graphene has been the object of a great deal of studies, aimed at understanding the fundamental relaxation mechanisms [1,2]. According to the band structure of graphene (Fig. 1(a)) absorption of a photon of frequency v promotes an electron from an energy hv/2 below the Fermi level in the valence band to an energy hv/2 above the Fermi level in the conduction band. Ultrafast photoexcitation, therefore, creates a strongly non-equilibrium (non-thermal) distribution of electrons in the conduction band (and holes in the valence band), consisting of two peaks at $\pm hv/2$ with respect to the Fermi level (see Fig. 1(a)).

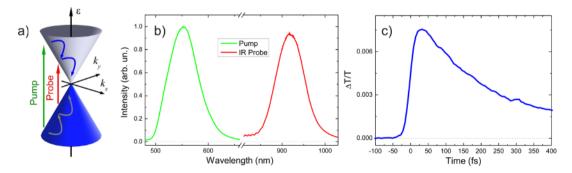


Fig. 1. (a) Sketch of the band structure of a single layer of grapheme and of the pump-probe experiment: the pump pulse excites a non-thermal electronic distribution that is probed at lower energies; (b) pump and probe pulse spectra; (c) $\Delta T/T$ time trace at the 860 nm probe wavelength.

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The primary relaxation process is thermalization due to electron-electron (e-e) interaction, giving rise to an equilibrated Fermi-Dirac (FD) electron distribution with a well defined temperature, higher than that of the lattice. The hot electrons subsequently reach thermal equilibrium with the colder lattice via electron-phonon (e-ph) scattering. These equilibration processes change the transient absorption spectrum over a wide range of energies and an ultrafast timescale. Their time-domain observation calls therefore for the combination of very short pulsewidths and broad spectral tunability.

2 Experiments

A large body of experimental work on ultrafast spectroscopy of graphene is available [1-4]. However, so far, most studies have been performed with a time resolution which is too low to observe e-e scattering dynamics and thus have probed an equilibrated hot electron/hole distribution, established within the pump pulse duration (~100-150 fs). These studies have revealed the dynamics of carrier cooling through interaction with the lattice. A number of theoretical studies [5] and indirect experimental evidence [4] however point to an extremely fast e-e relaxation, occurring on the 10-fs timescale. Here we perform pump-probe spectroscopy on graphene using two-color few-optical-cycle pulses. We impulsively excite optical transitions with an ultra-broadband 7-fs pulse centered at 2.25 eV (2-2.5 eV bandwidth) and probe with a red-shifted 13-fs pulse covering the 1.45-1.2 eV range. The instrumental response function (IRF) of our apparatus (full width at half maximum of the pump-probe cross-correlation) is ~15 fs [6,7]. The combination of high time resolution and broad spectral coverage allows capturing the transition from the non-thermal to a FD electron/hole distribution.

Pump-probe experiments are carried out on single-layer graphene films grown by chemical vapor deposition and transferred onto a 100- μ m-thick fused silica substrate. A portion of the substrate is not covered with graphene, thus allowing the measurement of the nonlinear response of the substrate by a simple transverse translation of the sample. In our experiments we observe a prompt rise of the photobleaching signal in the near-IR, that already points out to an ultrafast e-e relaxation, taking place over a timescale comparable to our IRF. Time traces at selected probe wavelengths display a biexponential decay (fig. 1(c)), with a first time constant $\tau 1 \sim 160$ fs, and a second longer time constant that is not addressed in this study. The first decay is assigned to cooling of the hot electron/hole distribution via interaction with optical phonons, while the longer decay is due to relaxation of the thermalized electron/phonon bath by anharmonic decay of the hot phonons.

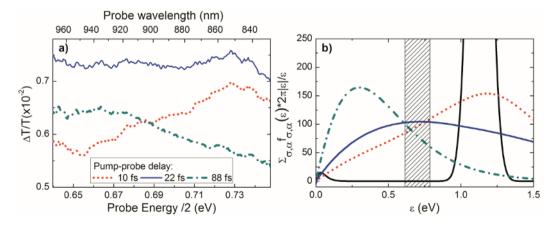


Fig. 2. (a) Transient spectra at selected delays after pumping with a 7-fs visible pulse. The change in slope shows the evolution of the impulsively excited electron distribution to the thermal equilibrium; (b) calculations of the electronic distribution at different delays (thick solid line $\tau_0=0$; dotted τ_1 , dash-dotted τ_2). The probe window is marked with the shaded area.

A deeper insight into the dynamical processes leading to e-e thermalization can be obtained by plotting $\Delta T/T$ spectra at selected probe delays (Fig. 2(a)). At early times (10 fs), the $\Delta T/T$ spectrum has a positive slope, peaking at higher energy; then it progressively flattens (22 fs) and changes to a negative slope, which is retained and then magnified at longer delays.

3 Results

To understand the data we recall that the $\Delta T/T$ signal for single-layer graphene is the transient electron/hole distribution function induced by the pump and explored at time τ . The sub-10-fs 2.25-eV pump pulse creates an electron distribution peaking at ~1.12 eV above the Fermi level, while the probe pulse interrogates the 0.6-0.72 eV interval.

At early times, therefore, we will observe the tail of this distribution, which has a positive slope. On the other hand for a thermal distribution the $\Delta T/T$ spectrum has a negative slope peaking at lower photon energies. The change of slope of the $\Delta T/T$ spectrum thus captures the transition from the non-thermal to the thermal regime, which is completed within ~30 fs. Fig. 2(b) reports a calculation of the transient electronic distribution above Fermi level that shows how, at early times, the electronic distribution (solid line) is still peaked at higher energy and then relaxes to a thermal distribution only at longer times (dash-dotted line). The observed dynamics do not exhibit a significant dependence on the excitation density. By moving from multichannel to single-wavelength detection, we were able to reduce the fluence by a factor of 20, and saw a substantially unchanged dynamics.

In conclusion, we exploit the very high temporal resolution of our two-color pump-probe scheme to observe the early times in the relaxation dynamics of out-of-equilibrium electrons in single layer graphene. The ultrafast timescale of this process is strongly related to the peculiar band structure and the electronic properties of this fascinating material.

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